

## High-Power Packaged GaAs FET

### Description

The CLY2 is a high-breakdown voltage GaAs FET designed for PA driver applications in the 400 MHz to 3 GHz frequency range. It is ideal for portable PA applications in mobile phones and portable WLAN transceivers due to its easy matching and excellent linearity. The CLY2 exhibits +23.5 dBm output power with +3V V<sub>D</sub> at 1.8 GHz with an associated gain of 14.5 dB. Power added efficiencies to 55% are achievable.

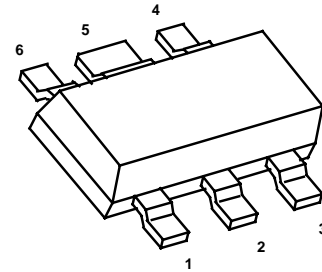
### Features

- For frequencies up to 3 GHz
- Wide operating voltage range: 2 to 6 V
- P<sub>OUT</sub> 23.5 dBm typical at V<sub>D</sub>=3V, f=1.8GHz
- High efficiency: better than 55 %
- Nfmin 0.79 dB typical at 900 MHz
- Low Cost

### Applications

- Power Amplifiers for WLAN transceivers
- Driver Amplifiers for WLAN or mobile phone basestations
- Low Noise Amplifier for basestations and antenna amplifiers

### Package Outline, MW6



#### Pin Configuration:

- 1 & 6: Gate
- 2 & 5: Source
- 3 & 4: Drain

## CLY2 Datasheet

### Maximum Ratings

Parameter	Symbol	Values	Unit
Drain-source voltage	$V_{DS}$	9	V
Drain-gate voltage	$V_{DG}$	12	V
Gate-source voltage	$V_{GS}$	-6	V
Drain current	$I_D$	600	mA
Channel temperature	$T_{Ch}$	150	°C
Storage temperature	$T_{stg}$	-55...+150	°C
Total power dissipation ( $T_S \leq 50$ °C) <sup>1)</sup>	$P_{tot}$	900	mW

### Thermal Resistance

Channel-soldering point <sup>1)</sup>	$R_{thChS}$	$\leq 110$	K/W
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<sup>1)</sup> $T_S$ : Temperature at soldering point

### Electrical Characteristics

( $T_A = 25^\circ\text{C}$  , unless otherwise specified)

Parameter	Symbol	min	typ	max	Unit
Drain-source saturation current $V_{DS} = 3\text{ V}$ $V_{GS} = 0\text{ V}$	$I_{DSS}$	300	450	650	mA
Drain-source pinch-off current $V_{DS} = 3\text{ V}$ $V_{GS} = -3.8\text{ V}$	$I_D$	-	5	50	$\mu\text{A}$
Gate pinch-off current $V_{DS} = 3\text{ V}$ $V_{GS} = -3.8\text{ V}$	$I_G$	-	5	20	$\mu\text{A}$
Pinch-off Voltage $V_{DS} = 3\text{ V}$ $I_D = 50\mu\text{A}$	$V_{GS(p)}$	-3.8	-2.8	-1.8	V
Small Signal Gain*) $V_{DS} = 5\text{ V}$ $I_D = 180\text{ mA}$ $f = 1.8\text{ GHz}$ $P_{in} = -5\text{ dBm}$	$G$	-	15.5	-	dB
Small Signal Gain*) $V_{DS} = 3\text{ V}$ $I_D = 180\text{ mA}$ $f = 1.8\text{ GHz}$ $P_{in} = -5\text{ dBm}$	$G$	-	14.5	-	dB
Output Power $V_{DS} = 3\text{ V}$ $I_D = 180\text{ mA}$ $f = 1.8\text{ GHz}$ $P_{in} = 10\text{ dBm}$	$P_O$	22.5	23.5	-	dBm

## CLY2 Datasheet

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### ***Electrical Characteristics (cont)***

1dB-Compression Point $V_{DS} = 3\text{ V}$ $I_D = 180\text{ mA}$ $f = 1.8\text{ GHz}$	$P_{1dB}$	-	23.5	-	dBm
1dB-Compression Point $V_{DS} = 5\text{ V}$ $I_D = 180\text{ mA}$ $f = 1.8\text{ GHz}$	$P_{1dB}$	-	27.0	-	dBm
Power Added Efficiency $V_{DS} = 3\text{ V}$ $I_D = 180\text{ mA}$ $f = 1.8\text{ GHz}$ $P_{in} = 10\text{ dBm}$	PAE	-	55	-	%
Noise figure $V_{DS} = 3\text{ V}$ $I_D = 180\text{ mA}$ $f = 1.8\text{ GHz}$	NF		1.48		dB

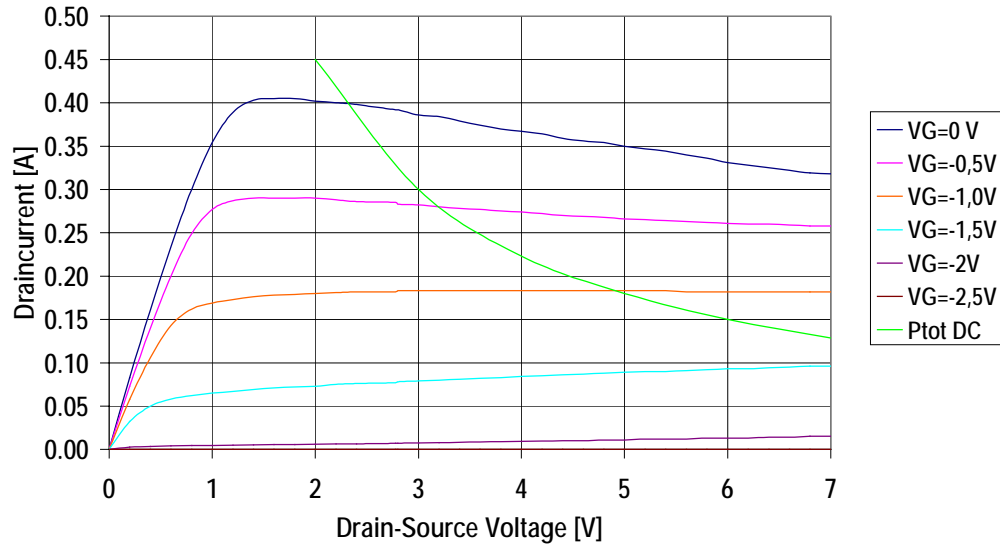
\*) Matching conditions for maximum small signal gain (not identical with power matching conditions!)

\*\*) Power matching conditions:  $f=1.8\text{GHz}$ :

Source Match:  $\Gamma_{ms}$ : MAG = 0.74, ANG 132°; Load Match:  $\Gamma_{ml}$ : ;MAG 0.61, ANG -153°

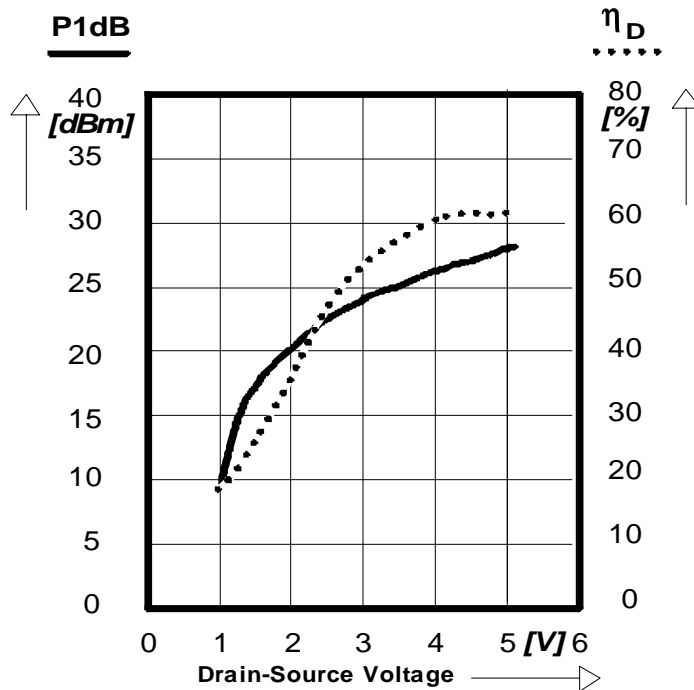
**Electrical Characteristics (cont)**

**Output characteristics**



**Compression Power vs. Drain-Source Voltage**

f = 1.8GHz; IDS = 0.5 Idss



## Electrical Characteristics (cont)

### Typical Common Source S-Parameters and noise data

$$V_{DS} = 3 \text{ V} \quad I_D = 180 \text{ mA} \quad Z_0 = 50 \ \Omega$$

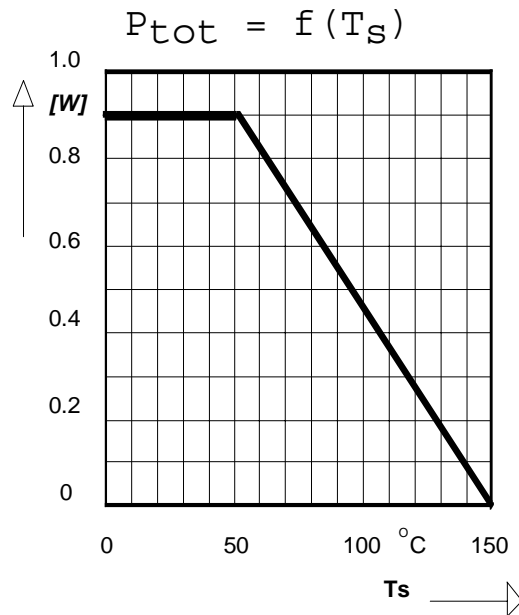
Freq. [GHz]	S11	<S11	S21	<S21	S12	<S12	S22	<S22
100	0.992	-13.3	10.120	170.7	0.008	101.1	0.115	-34.6
200	0.974	-26.4	9.778	162.6	0.014	74.1	0.140	-57.5
300	0.950	-38.6	9.278	154.7	0.021	74.0	0.171	-72.3
400	0.922	-49.5	8.683	147.8	0.025	68.0	0.200	-82.0
500	0.896	-59.1	8.042	141.8	0.031	64.8	0.226	-89.1
600	0.871	-67.1	7.444	137.0	0.033	63.0	0.248	-93.8
700	0.849	-74.0	6.880	132.5	0.036	60.6	0.267	-96.9
800	0.828	-79.9	6.373	129.1	0.038	60.2	0.284	-98.8
900	0.813	-85.0	5.900	125.9	0.039	59.1	0.299	-100.1
1,000	0.800	-89.2	5.485	123.4	0.041	59.5	0.312	-100.4
1,100	0.790	-92.6	5.110	121.3	0.041	59.4	0.323	-100.5
1,200	0.780	-95.5	4.780	119.3	0.043	60.2	0.335	-100.0
1,300	0.773	-97.7	4.498	117.7	0.043	61.6	0.345	-99.3
1,400	0.766	-99.6	4.225	116.2	0.044	62.3	0.354	-98.2
1,500	0.760	-100.9	3.987	115.3	0.045	64.1	0.364	-97.1
1,600	0.754	-102.0	3.769	114.4	0.045	65.9	0.372	-95.7
1,700	0.751	-102.7	3.588	113.6	0.045	67.7	0.380	-94.3
1,800	0.748	-103.3	3.426	112.9	0.046	70.0	0.388	-92.6
1,900	0.743	-103.5	3.268	112.3	0.046	71.8	0.397	-90.9
2,000	0.741	-103.8	3.119	111.7	0.047	74.525	0.404	-89.2

f	$F_{min}$	$\Gamma_{opt}$		$R_n$	$r_n$
GHz	dB	MAG	ANG	$\Omega$	-
0.9	0.79	0.564	61	13.4	0.267
1.8	1.47	0.585	99	13.6	0.272

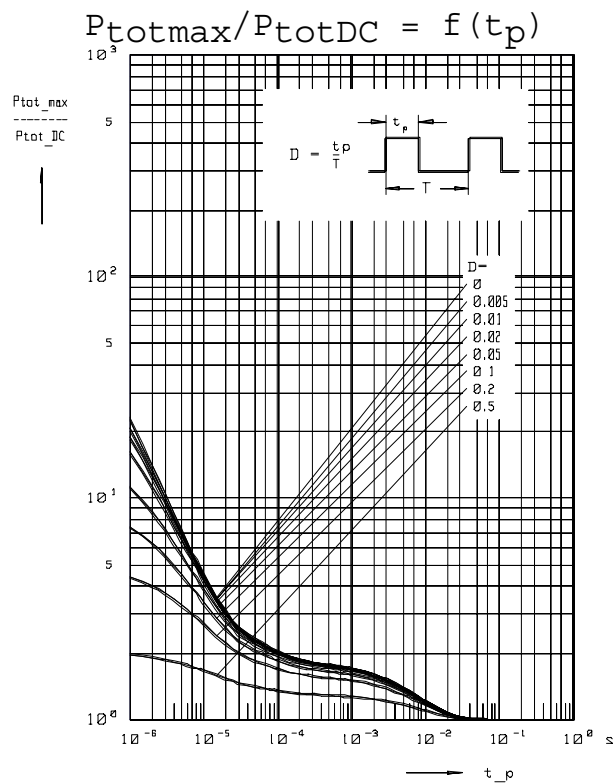
Additional S-Parameter and noise data available on data disc!

**Electrical Characteristics (cont)**

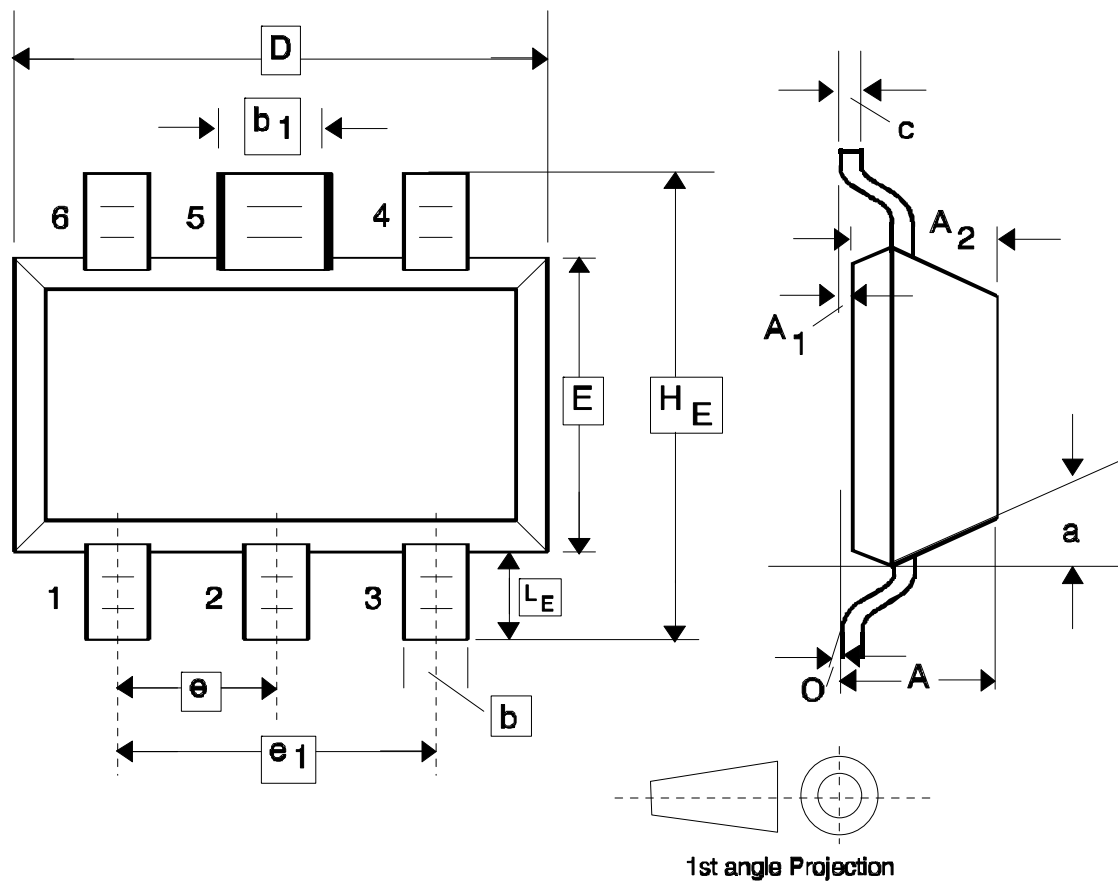
**Total Power Dissipation**



**Permissible Pulse Load**



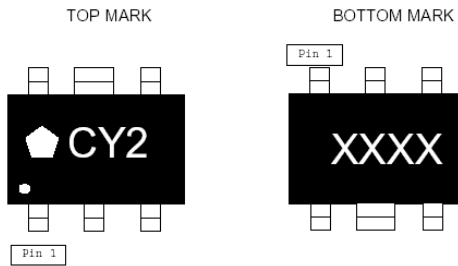
**Package Dimensions**



Dim.	min.	nom.	max.	Gradient	Remark
A			1.1		
A <sub>1</sub>			0.1		
A <sub>2</sub>			1.0		
b		0.3			
b <sub>1</sub>		0.6			
c	0.08		0.15		
D	2.8		3.0		
E	1.2		1.4		
e		0.95			
e <sub>1</sub>		1.9			
H <sub>E</sub>			2.6		
L <sub>E</sub>			0.6		
a				max 10°	1
q				2°...30°	

# CLY2 Datasheet

## Package Marking



## Package Orientation on Reel



## Ordering Information

Type	Marking	Pin Configuration						Package 1)
		1	2	3	4	5	6	
CLY 2	CY2	G	S	D	D	S	G	MW 6

## Additional Information

This part is compliant with RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

The part is rated Moisture Sensitivity Level 1 at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

ESD: **E**lectro**s**tatic **d**ischarge sensitive device. Observe handling Precautions.

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